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With the advance of semiconductors and ubiquitous computing, the use of system-on-a-chip (SoC) has become an essential technique to reduce product cost. With this progress and continuous reduction of feature sizes, and the development of very large-scale integration (VLSI) circuits, addressing the harder problems requires fundamental understanding of circuit and layout design issues. Furthermore, engineers can often develop their physical intuition to estimate the behavior of circuits rapidly without relying predominantly on computer-aided design (CAD) tools. Introduction to VLSI Systems: A Logic, Circuit, and System Perspective addresses the need for teaching such a topic in terms of a logic, circuit, and system design perspective. To achieve the above-mentioned goals, this classroom-tested book focuses on: Implementing a digital system as a full-custom integrated circuit Switch logic design and useful paradigms that may apply to various static and dynamic logic families The fabrication and layout designs of complementary metal-oxide-semiconductor (CMOS) VLSI Important issues of modern CMOS processes, including deep submicron devices, circuit optimization, interconnect modeling and optimization, signal integrity, power integrity, clocking and timing, power dissipation, and electrostatic discharge (ESD) Introduction to VLSI Systems builds an understanding of integrated circuits from the bottom up, paying much attention to logic circuit, layout, and system designs. Armed with these tools, readers can not only comprehensively understand the features and limitations of modern VLSI technologies, but also have enough background to adapt to this ever-changing field.

As the complexity and the density of VLSI chips increase with shrinking design rules, the evaluation of long-term reliability of MOS VLSI circuits is becoming an important problem. The assessment and improvement of reliability on the circuit level should be based on both the failure mode analysis and the basic understanding of the physical failure mechanisms observed in integrated circuits. Hot-carrier induced degradation of MOS transistor characteristics is one of the primary mechanisms affecting the long-term reliability of MOS VLSI circuits. It is likely to become even more important in future generation chips, since the downward scaling of transistor dimensions without proportional scaling of the operating voltage aggravates this problem. A thorough understanding of the physical mechanisms leading to hot-carrier related degradation of MOS transistors is a prerequisite for accurate circuit reliability evaluation. It is also being recognized that important reliability concerns other than the post-manufacture reliability qualification need to be addressed rigorously early in the design phase. The development and use of accurate reliability simulation tools are therefore crucial for early assessment and improvement of circuit reliability : Once the long-term reliability of the circuit is estimated through simulation, the results can be compared with predetermined reliability specifications or limits. If the predicted reliability does not satisfy the requirements, appropriate design modifications may be carried out to improve the resistance of the devices to degradation.

This practical, tool-independent guide to designing digital circuits takes a unique, top-down approach, reflecting the nature of the design process in industry. Starting with architecture design, the book comprehensively explains the why and how of digital circuit design, using the physics designers need to know, and no more.

In this book, a variety of topics related to Very-Large-Scale Integration (VLSI) is extensively discussed. The topics encompass the physics of VLSI transistors, the process of integrated chip design and fabrication and the applications of VLSI devices. It is intended to provide information on the latest advancement of VLSI technology to researchers, physicists as well as engineers working in the field of semiconductor manufacturing and VLSI design.

This book constitutes the refereed proceedings of the Second International Conference on Advances in Communication, Network, and Computing, CNC 2011, held in Bangalore, India, in March 2011. The 41 revised full papers, presented together with 50 short papers and 39 poster papers, were carefully reviewed and selected for inclusion in the book. The papers feature current research in the field of Information Technology, Networks, Computational Engineering, Computer and Telecommunication Technology, ranging from theoretical and methodological issues to advanced applications.

This edition presents broad and in-depth coverage of the entire field of modern CMOS VLSI Design. The authors draw upon extensive industry and classroom experience to introduce today's most advanced and effective chip design practices.

Silicon-On-Insulator (SOI) CMOS technology has been regarded as another major technology for VLSI in addition to bulk CMOS technology. Owing to the buried oxide structure, SOI technology offers superior CMOS devices with higher speed, high density, and reduced second order effects for deep-submicron low-voltage, low-power VLSI circuits applications. In addition to VLSI applications, and because of its outstanding properties, SOI technology has been used to realize communication circuits, microwave devices, BiCMOS devices, and even fiber optics applications. CMOS VLSI Engineering: Silicon-On-Insulator addresses three key factors in engineering SOI CMOS VLSI - processing technology, device modelling, and circuit designs are all covered with their mutual interactions. Starting from the SOI CMOS processing technology and the SOI CMOS digital and analog circuits, behaviors of the SOI CMOS devices are presented, followed by a CAD program, ST-SPICE, which incorporates models for deep-submicron fully-depleted mesa-isolated SOI CMOS devices and special purpose SOI devices including polysilicon TFTs. CMOS VLSI Engineering: Silicon-On-Insulator is written for undergraduate senior students and first-year graduate students interested in CMOS VLSI. It will also be suitable for electrical engineering professionals interested in microelectronics.

Beginning with discussions on the operation of electronic devices and analysis of the nucleus of digital design, the text addresses: the impact of interconnect, design for low power, issues in timing and clocking, design methodologies, and the effect of design automation on the digital design perspec-

tive.

This modern, pedagogic textbook from leading author Behzad Razavi provides a comprehensive and rigorous introduction to CMOS PLL design, featuring intuitive presentation of theoretical concepts, extensive circuit simulations, over 200 worked examples, and 250 end-of-chapter problems. The perfect text for senior undergraduate and graduate students.

This is the only comprehensive book in the market for engineers that covers the design of CMOS and bipolar analog integrated circuits. The fifth edition retains its completeness and updates the coverage of bipolar and CMOS circuits. A thorough analysis of a new low-voltage bipolar operational amplifier has been added to Chapters 6, 7, 9, and 11. Chapter 12 has been updated to include a fully differential folded cascode operational amplifier example. With its streamlined and up-to-date coverage, more engineers will turn to this resource to explore key concepts in the field.

Telecommunications is fundamental to modern society, with nearly everyone on the planet having access to a mobile phone, Wi-Fi, or satellite terrestrial broadcast systems. This book is a concise analysis of both the basics of telecommunications as well as numerous advanced systems. It begins with a discussion of why we perform modulation of a carrier signal, continuing with a study of noise affecting all telecommunications links, be they digital or analogue in form. Digital communications techniques are examined in Modern Telecommunications: Basic Principles and Practices. Such an examination is crucial since radio, television, and satellite broadcasts are transmitted using a digital format. Analogue modulations are also considered. The logic behind such an investigation is because, whereas most broadcast systems are moving towards digital transmission, analogue techniques are still very much prevalent (most notably with AM and FM broadcasts). A topic that is often neglected in text books on telecommunications but is at the forefront of Modern Telecommunications concerns transmission lines. This is an important area of work since every length of coaxial cable used to convey signals from an antenna to a receiver is a transmission line. It is vitally important that a transmission line linking a transmitter to the antenna is matched and this topic is explored in great detail in several chapters dealing with Smith charts. Explains the background behind digital TV and radio as well as the legacy of analogue transmissions. Presents materials in a way that minimizes mathematics, making the topic more approachable and interesting to users. Provides a look at familiar systems that readers encounter in their everyday life (including mobile phones, Wi-Fi hotspots, satellites, digital TV, etc.). Demonstrates techniques and topics through end-of-chapter problems. Presents materials in an introductory form, making the information easily understandable and suitable for an undergraduate option course.

Offers comprehensive coverage of digital CMOS circuit design, as well as addressing technology issues highlighted by the widespread use of nanometer-scale CMOS technologies.

A transistor-level, design-intensive overview of high speed and high frequency monolithic integrated circuits for wireless and broadband systems from 2 GHz to 200 GHz, this comprehensive text covers high-speed, RF, mm-wave, and optical fibre circuits using nanoscale CMOS, SiGe BiCMOS, and III-V technologies. Step-by-step design methodologies, end-of chapter problems, and practical simulation and design projects are provided, making this an ideal resource for senior undergraduate and graduate courses in circuit design. With an emphasis on device-circuit topology interaction and optimization, it gives circuit designers and students alike an in-depth understanding of device structures and process limitations affecting circuit performance. Physical Design for Multichip Modules collects together a large body of important research work that has been conducted in recent years in the area of Multichip Module (MCM) design. The material consists of a survey of published results as well as original work by the authors. All major aspects of MCM physical design are discussed, including interconnect analysis and modeling, system partitioning and placement, and multilayer routing. For readers unfamiliar with MCMs, this book presents an overview of the different MCM technologies available today. An in-depth discussion of various recent approaches to interconnect analysis are also presented. Remaining chapters discuss the problems of partitioning, placement, and multilayer routing, with an emphasis on timing performance. For the first time, data from a wide range of sources is integrated to present a clear picture of a new, challenging and very important research area. For students and researchers looking for interesting research topics, open problems and suggestions for further research are clearly stated. Points of interest include : Clear overview of MCM technology and its relationship to physical design; Emphasis on performance-driven design, with a chapter devoted to recent techniques for rapid performance analysis and modeling of MCM interconnects; Different approaches to multilayer MCM routing collected together and compared for the first time; Explanation of algorithms is not overly mathematical, yet is detailed enough to give readers a clear understanding of the approach; Quantitative data provided wherever possible for comparison of different approaches; A comprehensive list of references to recent literature on MCMs provided.

This textbook includes discussions of such topics as the environment, the debt case, export-led industrialization, import substitution industrialization, growth theory and technological capability.

Why a book on latchup? Latchup has been, and continues to be, a potentially serious CMOS reliability concern. This concern is becoming more widespread with the ascendancy of CMOS as the dominant VLSI technology, particularly as parasitic bipolar characteristics continue to improve at ever smaller dimensions on silicon wafers with ever lower defect densities. Although many successful parts have been marketed, latchup solutions have often been ad hoc. Although latchup avoidance techniques have been previously itemized, there has been little quantitative evaluation of prior latchup fixes. What is needed is a more general, more systematic treatment of the latchup problem. Because of the wide variety of CMOS technologies and

the long term interest in latchup, some overall guiding principles are needed. Appreciating the variety of possible triggering mechanisms is key to a real understanding of latchup. This work reviews the origin of each and its effect on the parasitic structure. Each triggering mechanism is classified according to a new taxonomy.

This textbook is ideal for senior undergraduate and graduate courses in RF CMOS circuits, RF circuit design, and high-frequency analog circuit design. It is aimed at electronics engineering students, as well as IC design engineers in the field, who wish to gain a deeper understanding of circuit fundamentals and go beyond the widely-used automated design procedures. A design-centric approach is adopted in order to bridge the gap between fundamental analog electronic circuits textbooks and more advanced RF IC design texts. The structure and operation of the building blocks of high-frequency ICs are introduced in a systematic manner, with an emphasis on transistor-level operation, the influence of device characteristics and parasitic effects, and input-output behavior in the time and frequency domains. This second edition has been revised extensively to expand and clarify some of the key topics and to provide a wide range of design examples and problems. New material has been added for basic coverage of core topics, such as wide-band LNAs, noise feedback concept and noise cancellation, inductive-compensated band widening techniques for flat-gain or flat-delay characteristics, and basic communication system concepts that exploit the convergence and co-existence of Analog and Digital building blocks in RF systems. A new chapter (Chapter 5) has been added on Noise and Linearity, addressing key topics in a comprehensive manner. All of the other chapters have also been revised and largely re-written, with the addition of numerous solved design examples and exercise problems. Designed for senior undergraduate and graduate courses in RF CMOS circuits, RF circuit design, and high-frequency analog circuit design; Uses simple circuit models to enable a robust understanding of high-frequency design fundamentals; Employs solved design examples to familiarize the reader with the design flow, starting with knowledge-based and model-based hand-design and progressing to SPICE simulations; Introduces fine-tuning procedures in circuit design with an emphasis on key trade-offs; Demonstrates key criteria and parameters that are used to describe system-level performance.

Regular Fabrics in Deep Sub-Micron Integrated-Circuit Design discusses new approaches to better timing-closure and manufacturability of DSM Integrated Circuits. The key idea presented is the use of regular circuit and interconnect structures such that area/delay can be predicted with high accuracy. The co-design of structures and algorithms allows great opportunities for achieving better final results, thus closing the gap between IC and CAD designers. The regularities also provide simpler and possibly better manufacturability. In this book we present not only algorithms for solving particular sub-problems but also systematic ways of organizing different algorithms in a flow to solve the design problem as a whole. A timing-driven chip design flow is developed based on the new structures and their design algorithms, which produces faster chips in a shorter time.

The third edition of Hodges and Jackson's Analysis and Design of Digital Integrated Circuits has been thoroughly revised and updated by a new co-author, Resve Saleh of the University of British Columbia. The new edition combines the approachability and concise nature of the Hodges and Jackson classic with a complete overhaul to bring the book into the 21st century. The new edition has replaced the emphasis on BiPolar with an emphasis on CMOS. The outdated MOS transistor model used throughout the book will be replaced with the now standard deep submicron model. The material on memory has been expanded and updated. As well the book now includes more on SPICE simulation and new problems that reflect recent technologies. The emphasis of the book is on design, but it does not neglect analysis and has as a goal to provide enough information so that a student can carry out analysis as well as be able to design a circuit. This book provides an excellent and balanced introduction to digital circuit design for both students and professionals.

The book provides a comprehensive coverage of different aspects of low power circuit synthesis at various levels of design hierarchy; starting from the layout level to the system level. For a seamless understanding of the subject, basics of MOS circuits has been introduced at transistor, gate and circuit level; followed by various low-power design methodologies, such as supply voltage scaling, switched capacitance minimization techniques and leakage power minimization approaches. The content of this book will prove useful to students, researchers, as well as practicing engineers.

Exponential improvement in functionality and performance of digital integrated circuits has revolutionized the way we live and work. The continued scaling down of MOS transistors has broadened the scope of use for circuit technology to the point that texts on the topic are generally lacking after a few years. The second edition of Digital Integrated Circuits: Analysis and Design focuses on timeless principles with a modern interdisciplinary view that will serve integrated circuits engineers from all disciplines for years to come. Providing a revised instructional reference for engineers involved with Very Large Scale Integrated Circuit design and fabrication, this book delves into the dramatic advances in the field, including new applications and changes in the physics of operation made possible by relentless miniaturization. This book was conceived in the versatile spirit of the field to bridge a void that had existed between books on transistor electronics and those covering VLSI design and fabrication as a separate topic. Like the first edition, this volume is a crucial link for integrated circuit engineers and those studying the field, supplying the cross-disciplinary connections they require for guidance in more advanced work. For pedagogical reasons, the author uses SPICE level 1 computer simulation models but introduces BSIM models that are indispensable for VLSI design. This enables users to develop a strong and intuitive sense of device and circuit design by drawing direct connections between the hand analysis and the SPICE models. With four new chapters, more than 200 new illustrations, numerous worked examples, case studies, and support provided on a dynamic website, this text significantly expands concepts presented in the first edition.

Low Power Design Methodologies presents the first in-depth coverage of all the layers of the design hierarchy, ranging from the technology, circuit, logic and architectural levels, up to the system layer. The book gives insight into the mechanisms of power dissipation in digital circuits and presents state of the art approaches to power reduction. Finally, it introduces a global view of low power design methodologies and how these are being captured in the latest design automation environments. The individual chapters are written by the leading researchers in the area, drawn from both industry and academia. Extensive references are included at the end of each chapter. Audience: A broad introduction for anyone interested in low power design. Can also be used as a text book for an advanced graduate class. A starting point for any aspiring researcher.

Contains the most extensive coverage of digital integrated circuits available in a single source. Provides complete qualitative descriptions of circuit operation followed by in-depth analytical analyses and spice simulations. The circuit families described in detail are transistor-transistor logic (TTL, STTL, and ASTTL), emitter-coupled logic (ECL), NMOS logic, CMOS logic, dynamic CMOS, BiCMOS structures and various GASFET technologies. In addition to

detailed presentation of the basic inverter circuits for each digital logic family, complete details of other logic circuits for these families are presented. This textbook deals with the analysis and design of analog CMOS integrated circuits, emphasizing recent technological developments and design paradigms that students and practicing engineers need to master to succeed in today's industry. Based on the author's teaching and research experience in the past ten years, the text follows three general principles: (1) Motivate the reader by describing the significance and application of each idea with real-world problems; (2) Force the reader to look at concepts from an intuitive point of view, preparing him/her for more complex problems; (3) Complement the intuition by rigorous analysis, confirming the results obtained by the intuitive, yet rough approach.

Based on the authors' expansive collection of notes taken over the years, Nano-CMOS Circuit and Physical Design bridges the gap between physical and circuit design and fabrication processing, manufacturability, and yield. This innovative book covers: process technology, including sub-wavelength optical lithography; impact of process scaling on circuit and physical implementation and low power with leaky transistors; and DFM, yield, and the impact of physical implementation.

The fourth edition of CMOS Digital Integrated Circuits: Analysis and Design continues the well-established tradition of the earlier editions by offering the most comprehensive coverage of digital CMOS circuit design, as well as addressing state-of-the-art technology issues highlighted by the widespread use of nanometer-scale CMOS technologies. In this latest edition, virtually all chapters have been re-written, the transistor model equations and device parameters have been revised to reflect the significant changes that must be taken into account for new technology generations, and the material has been reinforced with up-to-date examples. The broad-ranging coverage of this textbook starts with the fundamentals of CMOS process technology, and continues with MOS transistor models, basic CMOS gates, interconnect effects, dynamic circuits, memory circuits, arithmetic building blocks, clock and I/O circuits, low power design techniques, design for manufacturability and design for testability.

This book conveys an understanding of CMOS technology, circuit design, layout, and system design sufficient to the designer. The book deals with the technology down to the layout level of detail, thereby providing a bridge from a circuit to a form that may be fabricated. The early chapters provide a circuit view of the CMOS IC design, the middle chapters cover a sub-system view of CMOS VLSI, and the final section illustrates these techniques using a real-world case study.

Low-Power Digital VLSI Design: Circuits and Systems addresses both process technologies and device modeling. Power dissipation in CMOS circuits, several practical circuit examples, and low-power techniques are discussed. Low-voltage issues for digital CMOS and BiCMOS circuits are emphasized. The book also provides an extensive study of advanced CMOS subsystem design. A low-power design methodology is presented with various power minimization techniques at the circuit, logic, architecture and algorithm levels. Features: Low-voltage CMOS device modeling, technology files, design rules Switching activity concept, low-power guidelines to engineering practice Pass-transistor logic families Power dissipation of I/O circuits Multi- and low-VT CMOS logic, static power reduction circuit techniques State of the art design of low-voltage BiCMOS and CMOS circuits Low-power techniques in CMOS SRAMS and DRAMS Low-power on-chip voltage down converter design Numerous advanced CMOS subsystems (e.g. adders, multipliers, data path, memories, regular structures, phase-locked loops) with several design options trading power, delay and area Low-power design methodology, power estimation techniques Power reduction techniques at the logic, architecture and algorithm levels More than 190 circuits explained at the transistor level.

CD-ROM contains: AIM SPICE (from AIM Software) -- Micro-Cap 6 (from Spectrum Software) -- Silos III Verilog Simulator (from Simucad) -- Adobe Acrobat Reader 4.0 (from Adobe).

VERILOG HDL, Second Edition by Samir Palnitkar With a Foreword by Prabhu Goel Written for both experienced and new users, this book gives you broad coverage of Verilog HDL. The book stresses the practical design and verification perspective of Verilog rather than emphasizing only the language aspects. The information presented is fully compliant with the IEEE 1364-2001 Verilog HDL standard. Among its many features, this edition: Describes state-of-the-art verification methodologies; Provides full coverage of gate, dataflow (RTL), behavioral and switch modeling; Introduces you to the Programming Language Interface (PLI); Describes logic synthesis methodologies; Explains timing and delay simulation; Discusses user-defined primitives; Offers many practical modeling tips Includes over 300 illustrations, examples, and exercises, and a Verilog resource list. Learning objectives and summaries are provided for each chapter. About the CD-ROM The CD-ROM contains a Verilog simulator with a graphical user interface and the source code for the examples in the book. What people are saying about Verilog HDL - "Mr. Palnitkar illustrates how and why Verilog HDL is used to develop today's most complex digital designs. This book is valuable to both the novice and the experienced Verilog user. I highly recommend it to anyone exploring Verilog based design." - Rajeev Madhavan, Chairman and CEO, Magma Design Automation "This book is unique in its breadth of information on Verilog and Verilog-related topics. It is fully compliant with the IEEE 1364-2001 standard, contains all the information that you need on the basics, and devotes several chapters to advanced topics such as verification, PLI, synthesis and modeling techniques." - Michael McNamara, Chair, IEEE 1364-2001 Verilog Standards Organization This has been my favorite Verilog book since I picked it up in college. It is the only book that covers practical Verilog. A must have for beginners and experts." - Berend Ozceri, Design Engineer, Cisco Systems, Inc. "Simple, logical and well-organized material with plenty of illustrations, makes this an ideal textbook." - Arun K. Somani, Jerry R. Junkins Chair Professor, Department of Electrical and Computer Engineering, Iowa State University, Ames PRENTICE HALL Professional Technical Reference Upper Saddle River, NJ 07458 www.phptr.com ISBN: 0-13-044911-3

CMOS Digital Integrated Circuits: Analysis and Design is the most complete book on the market for CMOS circuits. Appropriate for electrical engineering and computer science, this book starts with CMOS processing, and then covers MOS transistor models, basic CMOS gates, interconnect effects, dynamic circuits, memory circuits, BiCMOS circuits, I/O circuits, VLSI design methodologies, low-power design techniques, design for manufacturability and design for testability. This book provides rigorous treatment of basic design concepts with detailed examples. It typically addresses both the computer-aided analysis issues and the design issues for most of the circuit examples. Numerous SPICE simulation results are also provided for illustration of basic concepts. Through rigorous analysis of CMOS circuits in this text, students will be able to learn the fundamentals of CMOS VLSI design, which is the driving force behind the development of advanced computer hardware.

System-on-a-chip (SoC) designs result in a wide range of high-complexity, high-value semiconductor products. As the technology scales towards smaller feature sizes and chips grow larger, a speed limitation arises due to an increased RC delay associated with interconnection wires. Innovative circuit techniques are required to achieve the speed needed for high-performance signal processing. Current sensing is considered as a promising circuit class since it is inherently faster than conventional voltage sense amplifiers. However, especially in SRAM, current sensing has rarely been used so far. Practical implementations are challenging because they require sophisticated analog circuit techniques in a digital environment. The objective of this book is to provide a systematic and comprehensive insight into current sensing techniques. Both theoretical and practical aspects are covered. Design guidelines are derived by systematic analysis of different circuit principles. Innovative concepts like compensation of the bit line multiplexer and auto-power-down will be explained based on theory and experimental results. The material will be interesting for design engineers in industry as well as researchers who want to learn about and apply current sensing techniques. The focus is on embedded SRAM but the material presented can

be adapted to single-chip SRAM and to any other current-providing memory type as well. This includes emerging memory technologies like magnetic RAM (MRAM) and Ovonic Unified Memory (OUM). Moreover, it is also applicable to array like structures such as CMOS camera chips and to circuits for signal transmission along highly capacitive busses.

Using the book and the software provided with it, the reader can build his/her own tester arrangement to investigate key aspects of analog-, digital- and mixed system circuits. Plan of attack based on traditional testing, circuit design and circuit manufacture allows the reader to appreciate a testing regime from the point of view of all the participating interests. Worked examples based on theoretical bookwork, practical experimentation and simulation exercises teach the reader how to test circuits thoroughly and effectively.

The second edition of VLSI Design is a comprehensive textbook designed for undergraduate students of electrical, electronics, and electronics and communication engineering. It provides a thorough understanding of the fundamental concepts and design of VLSI systems.